2SD1993

Silicon NPN epitaxial planer type

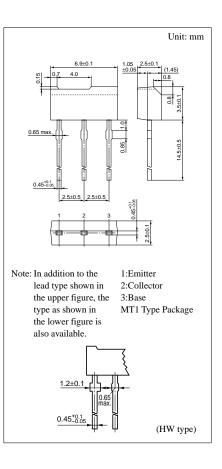
For low-frequency and low-noise amplification

Features

- Low noise voltage NV.
- High foward current transfer ratio h_{FE}.
- Allowing supply with the radial taping.

| ••••• ••• •••• •••• •••• ••••• ••••• | | | | | | |
|--------------------------------------|------------------|------------|------|--|--|--|
| Parameter | Symbol | Ratings | Unit | | | |
| Collector to base voltage | V _{CBO} | 55 | V | | | |
| Collector to emitter voltage | V _{CEO} | 55 | V | | | |
| Emitter to base voltage | V _{EBO} | 7 | V | | | |
| Peak collector current | I _{CP} | 200 | mA | | | |
| Collector current | I _C | 100 | mA | | | |
| Collector power dissipation | P _C | 400 | mW | | | |
| Junction temperature | Tj | 150 | °C | | | |
| Storage temperature | T _{stg} | -55 ~ +150 | °C | | | |
| | | | | | | |

Absolute Maximum Ratings (Ta=25°C)

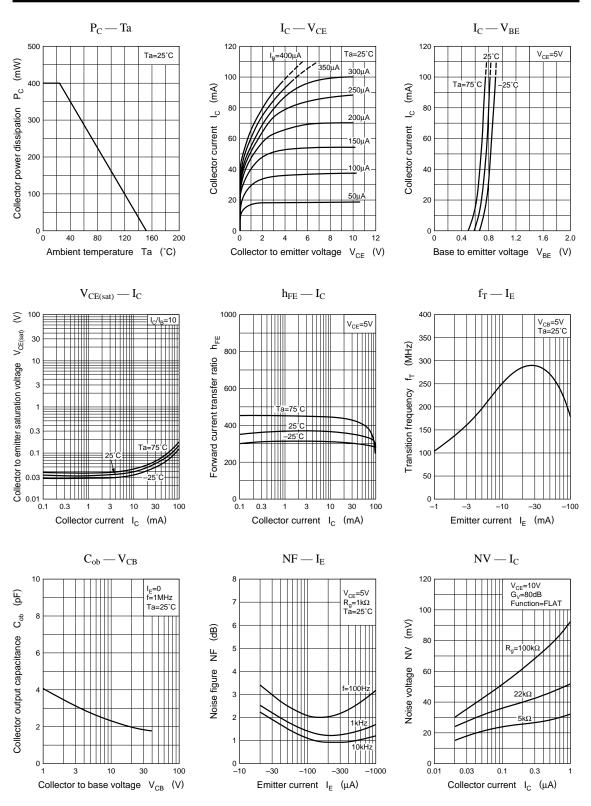


Electrical Characteristics (Ta=25°C)

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|----------------------|---|-----|-----|-----|-------|
| Collector cutoff current | I _{CBO} | $V_{CB} = 20V, I_E = 0$ | | | 100 | nA |
| | I _{CEO} | $V_{CE} = 20V, I_B = 0$ | | | 1 | μΑ |
| Collector to base voltage | V _{CBO} | $I_C = 10\mu A$, $I_E = 0$ | 55 | | | V |
| Collector to emitter voltage | V _{CEO} | $I_C = 2mA$, $I_B = 0$ | 55 | | | V |
| Emitter to base voltage | V _{EBO} | $I_{\rm E} = 10 \mu A, I_{\rm C} = 0$ | 7 | | | V |
| Forward current transfer ratio | h _{FE} * | $V_{CE} = 10V, I_C = 2mA$ | 210 | | 650 | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 10 {\rm mA}$ | | | 1.0 | V |
| Transition frequency | f _T | $V_{CB} = 10V, I_E = -2mA, f = 200MHz$ | | 200 | | MHz |
| Noise voltage | NV | $V_{CE} = 10V, I_C = 1mA, G_V = 80dB$ | | | 150 | mV |
| Noise voltage | | $R_g = 100k\Omega$, Function = FLAT | | | 150 | 111 V |

*hFE Rank classification

| Rank | R | S | Т |
|----------------------------|-----------|-----------|-----------|
| \mathbf{h}_{FE} | 210 ~ 340 | 290 ~ 460 | 360 ~ 650 |



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